					•		•					
5 1 b			<u>+</u>	DV DY0	VCD/00							
Please type	a plus sig	n (+) inside this b	ox. FO	HM PIO	/2B/08	T						
Substitute for form 1449A/PTO						Complete if Known						
						A	Application Number 10/624 2ad					
INFORMATION DISCLOSURE						Filing Date						
STATEMENT BY APPLICANT									Leo Mathew			
						Group Art Unit				282)		
(use as many sheets as necessary)										iek , V.		
Sheet	Sheet 1 of 1					Attorney Docket Number SC128			62TC			
												
		1					r documents	0-	45.06	Bases Columns Lines M	lhoro	
Examiner	Cite	U.S. Patent Document Number Kind Code*			man			ite of cation of	Pages, Columns, Lines, V	levant Passages or Relevant		
Initials*	No. '					of C	Applicant ited Document		Document	Figures Appear		
! 		(if known)		i '	Or Ollow Bocombin			D-YYYY	_			
		<u> </u>	T.		<u> </u>							
			$\forall \perp$									
	 											
·			-	$\overline{}$								
L	·			$\overline{}$	<u> </u>					<u> </u>		
· · · · · · · · · · · · · · · · · · ·				FORE	TON P	ATI	ENT DOCUMENTS					
Examiner	Cite	Foreign	Patent				Name of Patentee or	Date	of	Pages, Columns, Lines,	T F	
Initials*	No. '	Foreign Patent Document Office ³ Number ⁴ Kind Coo				M	Applicant of Cited		cation of Where Relevant			
		(if know			- 1A	X _ ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' '		Cited Document Passages or Relevant				
_				,		" [MM-0	YYYY-CC	Figures Appear		
						П						
											1	
					\neg							
		 		-,		┪				· · · · · · · · · · · · · · · · · · ·	1	
· · · · · · · · · · · · · · · · · · ·		 				-					 	
		 	•			-				 	 	
ļ	L	OTHER	DDIAI	ADT	NONLI	DAT	TENT LITERATUR	E DOCI	MENTS	<u> </u>	ш.	
Fuerrines		OTHER	PRIOR	CARI -	NON	PAI	ALLETTERS) title of	the article	When and	propriate), title of the item (boo	ok	
Examiner Initials*	Cite No. '	manazina i	me oi tr oumal	18 aumoi serial si	r (in CA vmnosii	100 J	catalog etc.) date or	ine(s) vo	lume-issue	number(s), publisher, city and	d/or	
111111111111111111111111111111111111111	1.0.	magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.										
حر ا	AA	Geppert, "Momentum Builds for Multiple-Gate Transistors," IEEE, Spectrum, pp. 1-3 (2003).										
W	` - `	Copport, montanti balla to manpio and mandiolog, man openially pp. 1 o (2000).										
10/												
ļ	100	Ob- #5:-55	r	. I - D I -	- \/:-		Dominanaa in Eutr	uro loo i	" Cilicon S	Stratogics pp. 1-4/2003	21	
 	AB	Onr, Fine	is and	I INP IC	SVIE	ior	Dominance in Full	ure ics,	Silicon s	Strategies, pp. 1-4 (2003	,).	
1 1 1												
	1											
 	AC	Nowek et al. "A Eupstianal EinEET DCCMOS SPAM Cell." IEEE 4 pgs. (2002)										
./c	1 40	Nowak et al., "A Functional FinFET-DGCMOS SRAM Cell," IEEE, 4 pgs., (2002).										
レクフ		·										
	'											
 	AD	Copy of rela	ted na	tent ar	nlicati	ion	10/074 732					
1//>	^5	Joby of Isla	.ou pa	norn ap	piioali		TOTAL TITUE					
🐧												

Signature YUTHE > 12 Considered 7 15 (0)

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

Examiner

Date

^{&#}x27;Unique citation designation number. 'See Kinds of U.S. Patent Documents. 'Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 'For Japanese patent documents, the indication of the year of the Emperor must precede the serial number of the patent document. 'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 'Applicant is to place a check mark here if English Language Translation is attached.